Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1854	((438/199) or (438/207) or (438/222) or (438/483)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/24 14:23
L2	6582	(si silicon) near2 (germanium ge) near2 (carbon c!) sigec sicge csige cgesi gesic gecsi	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 14:24
L3	766626	mask$4 photoresist pr	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 14:24
L4	235745	mosfet or (metal adj (oxide or insulat$4) adj semiconducor adj (fet or field)) or pmos or cmos or nmos or misfet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 14:24
L5	5147008	aperature opening gap hole	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 14:24
L6	1	(L3 with L5 and L2 and L4).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 14:24